



Features

- Four, six and eight channels of EMI filtering with integrated ESD protection
- Pi-style EMI filters in a capacitor-resistorcapacitor (C-R-C) network
- ±15kV ESD protection on each channel (IEC 61000-4-2 Level 4, contact discharge)
- ±30kV ESD protection on each channel (HBM)
- Greater than 25dB attenuation (typical) at 1 GHz
- UDFN package with 0.40mm lead pitch:
 - 4-ch. = 8-lead UDFN
 - 6-ch. = 12-lead UDFN
 - 8-ch. = 16-lead UDFN
- Tiny UDFN package size:
 - 8-lead: 1.7mm x 1.35mm x 0.5mm
 - 12-lead: 2.5mm x 1.35mm x 0.5mm
 - 16-lead: 3.3mm x 1.35mm x 0.5mm
- Increased robustness against vertical impacts during manufacturing process
- Lead-free version available

Applications

- LCD and Camera data lines in mobile handsets
- I/O port protection for mobile handsets, notebook computers, PDAs etc.
- EMI filtering for data ports in cell phones, PDAs or notebook computers.
- Wireless handsets
- Handheld PCs/PDAs
- LCD and camera modules

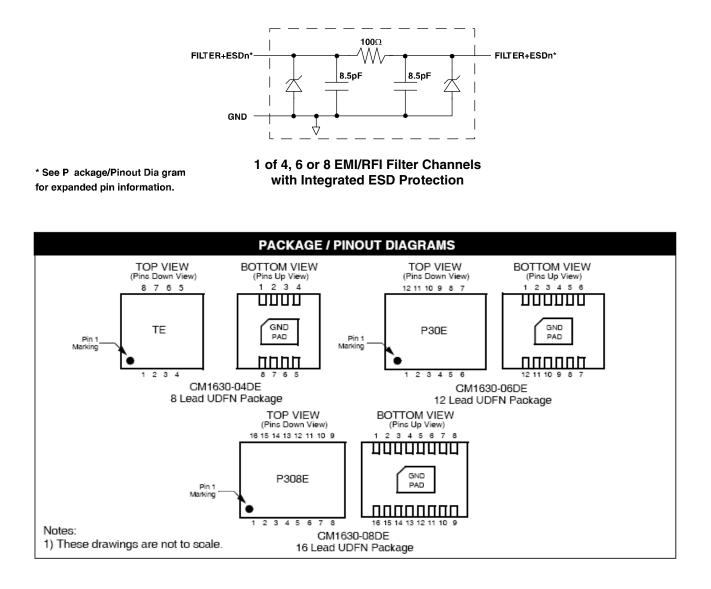
Product Description

The CM1630 is a family of pi-style EMI filter arrays with ESD protection, which integrates four, six and eight filters (C-R-C) in small form factor UDFN 0.40mm pitch packages. The CM1630 has component values of 8.5pF-100Ω-8.5pF per channel. The CM1630 has a cut-off frequency of 200MHz and can be used in applications with data rates up to 80Mbps. The parts include ESD diodes on every pin, which provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The ESD protection diodes safely dissipate ESD strikes of ±15kV, well beyond the maximum requirement of the IEC61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the pins are protected for contact discharges at greater than ±30kV.

These devices are particularly well-suited for portable electronics (e.g. wireless handsets, PDAs, notebook computers) because of their small package and easy-to-use pin assignments. In particular, the CM1630 is ideal for EMI filtering and protecting data and control lines for the I/O data ports, LCD display and camera interface in mobile handsets.

The CM1630 is housed in space-saving, low-profile 8-, 12- and 16-lead UDFN packages with a 0.4mm pitch and is available with lead-free finishing. This new small UDFN package provides up to 42% board space savings vs. the 0.50mm pitch UDFN packages.

Electrical Schematic



	PIN DESCRIPTIONS										
DEVICE PIN(s)						DEVICE PIN(s)		N(s)			
-04	-06	-08	NAME	DESCRIPTION		-04	-04 -06 -08		NAME	DESCRIPTION	
1	1	1	FILTER1	Filter + ESD Channel 1		8	12	16	FILTER1	Filter + ESD Channel 1	
2	2	2	FILTER2	Filter + ESD Channel 2		7	11	15	FILTER2	Filter + ESD Channel 2	
3	3	3	FILTER3	Filter + ESD Channel 3		6	10	14	FILTER3	Filter + ESD Channel 3	
4	4	4	FILTER4	Filter + ESD Channel 4		5	9	13	FILTER4	Filter + ESD Channel 4	
	5	5	FILTER5	Filter + ESD Channel 5			8	12	FILTER5	Filter + ESD Channel 5	
	6	6	FILTER6	Filter + ESD Channel 6			7	11	FILTER6	Filter + ESD Channel 6	
		7	FILTER7	Filter + ESD Channel 7		10		FILTER7	Filter + ESD Channel 7		
		8	FILTER8	Filter + ESD Channel 8				9	FILTER8	Filter + ESD Channel 8	
C	GND PA	D	GND	Device Ground							

Ordering Information

PART NUMBERING INFORMATION								
		Lead-free Finish						
Pins	Package	Ordering Part Number ¹	Part Marking					
8	UDFN-8	CM1630-04DE	TE					
12	UDFN-12	CM1630-06DE	P30E					
16	UDFN-16	CM1630-08DE	P308E					

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

Specifications

ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNITS
Storage Temperature Range	-65 to +150	°C
DC Power per Resistor	100	mW
DC Package Power Rating	500	mW

STANDARD OPERATING CONDITIONS							
PARAMETER	RATING	UNITS					
Operating Temperature Range	-40 to +85	°C					

	ELECTRICAL OPERATING CHARACTERISTICS (SEE NOTE1)									
SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNITS				
R	Resistance		80	100	120	Ω				
$C_{_{TOTAL}}$	Total Channel Capacitance	At 2.5VDC Reverse Bias, 1MHz, 30mVAC	14	17	22	pF				
С	Capacitance C1	At 2.5VDC Reverse Bias, 1MHz, 30mVAC	7	8.5	11	pF				
V_{diode}	Standoff Voltage	$I_{\text{DIODE}} = 10 \mu A$		6.0		V				
I _{leak}	Diode Leakage Current (reverse bias)	V _{DIODE} =+3.3V		0.1	1.0	μA				
V_{SIG}	Signal Clamp Voltage Positive Clamp Negative Clamp	$I_{LOAD} = 10mA$ $I_{LOAD} = -10mA$	5.6 -0.4	6.8 -0.8		V V				
V_{esd}	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2 Level 4	Note 2	±30 ±15			kV kV				
$R_{_{DYN}}$	Dynamic Resistance Positive Negative			2.3 0.9		Ω Ω				
f _c	Cut-off Frequency Z_{SOURCE} =50 Ω , Z_{LOAD} =50 Ω	Channel R = 100Ω , Channel C = $8.5pF$		200		MHz				
$A_{_{1GHz}}$	Absolute Attenuation @ 1GHz from 0dB Level	$Z_{\text{SOURCE}} = 50\Omega, Z_{\text{LOAD}} = 50\Omega,$ DC Bias = 0V; Notes 1 and 3		30		dB				
A _{800MHz - 6GHz}	Absolute Attenuation @ 800MHz to 6GHz from 0dB Level	$Z_{\text{SOURCE}} = 50\Omega, Z_{\text{LOAD}} = 50\Omega,$ DC Bias = 0V; Notes 1 and 3		25		dB				

Note 1: $T_A=25^{\circ}C$ unless otherwise specified. Note 2: ESD applied to input and output pins with respect to GND, one at a time. Note 3: Attenuation / RF curves characterized by a network analyzer using microprobes.

Performance Information

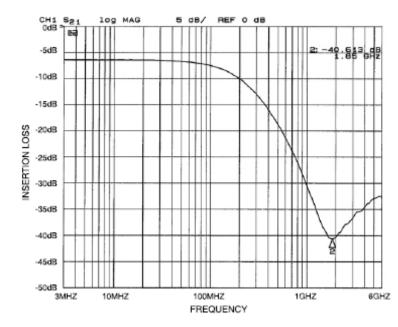


Figure 1. Insertion Loss vs. Frequency (FILTER1 Input to GND, CM1436-04DE)

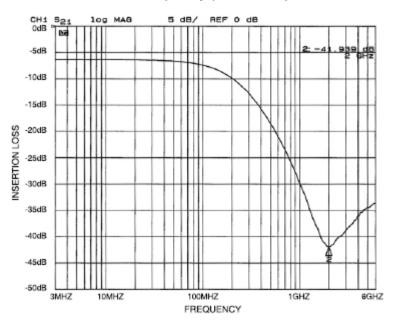


Figure 2. Insertion Loss vs. Frequency (FILTER2 Input to GND, CM1436-04DE)

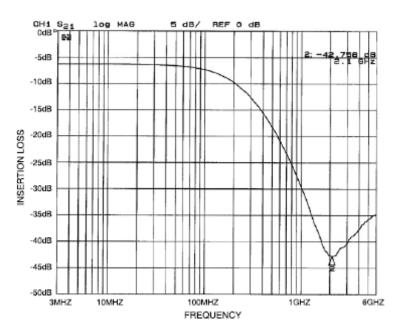


Figure 3. Insertion Loss vs. Frequency (FILTER3 Input to GND, CM1436-04DE)

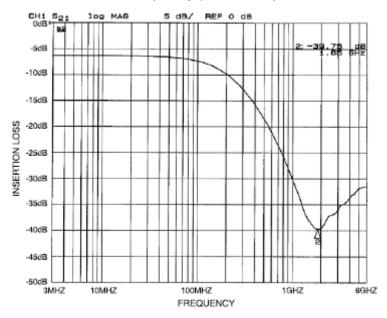


Figure 4. Insertion Loss vs. Frequency (FILTER4 Input to GND, CM1436-04DE)

Performance Information (cont'd)

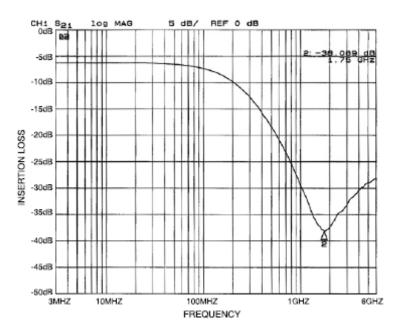


Figure 5. Insertion Loss vs. Frequency (FILTER1 Input to GND, CM1436-06DE)

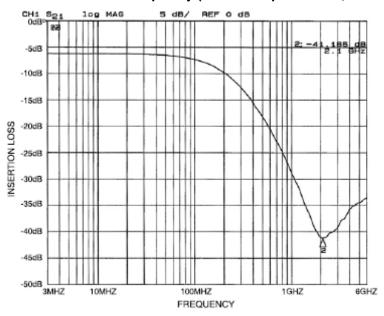
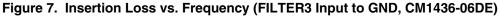


Figure 6. Insertion Loss vs. Frequency (FILTER2 Input to GND, CM1436-06DE)

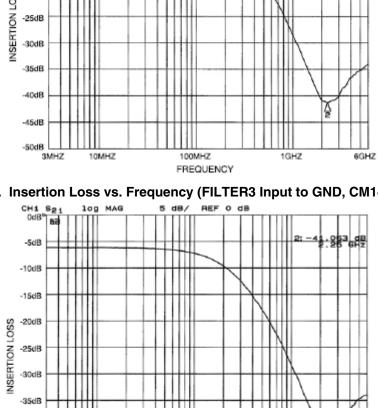
CH1 521 log MAG 5 dB/ REF 0 dB -5dB -10dB -15dB -20dB INSERTION LOSS -25dB -30dB -35dB -40dB ş -45dB -50dB 3MHZ 10MHZ 100MHZ 1GHZ FREQUENCY

Typical Filter Performance (T_A=25°C, DC Bias=0V, 50 Ohm Environment)



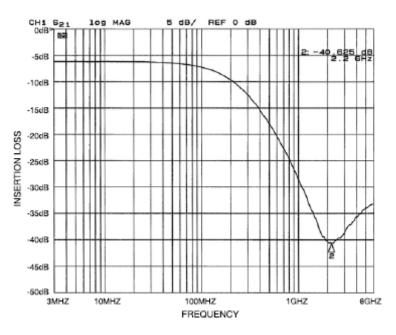
0dB⁴ 53 g -5dB -10dB -15dB -20dB INSERTION LOSS -25dB -30dB -35dB -40clB Å -45dB -50dB 10MHZ 100MHZ 3MHZ 1GHZ 6GHZ FREQUENCY

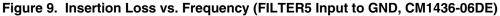
Figure 8. Insertion Loss vs. Frequency (FILTER4 Input to GND, CM1436-06DE)



Performance Information (cont'd)

Typical Filter Performance (T_A=25°C, DC Bias=0V, 50 Ohm Environment)





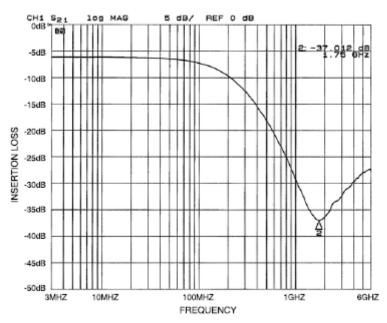


Figure 10. Insertion Loss vs. Frequency (FILTER6 Input to GND, CM1436-06DE)

Rev. 2 | Page 9 of 18 | www.onsemi.com

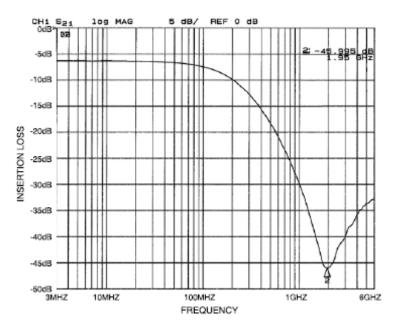


Figure 11. Insertion Loss vs. Frequency (FILTER1 Input to GND, CM1436-08DE)

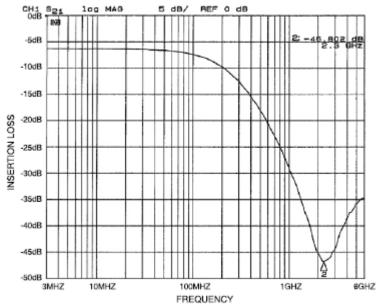


Figure 12. Insertion Loss vs. Frequency (FILTER2 Input to GND, CM1436-08DE)

Performance Information (cont'd)

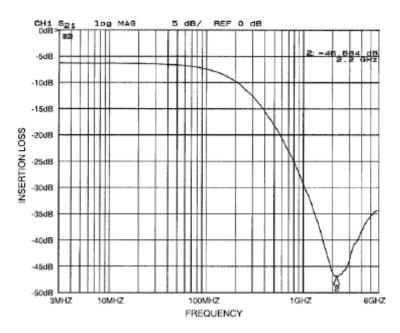


Figure 13. Insertion Loss vs. Frequency (FILTER3 Input to GND, CM1436-08DE)

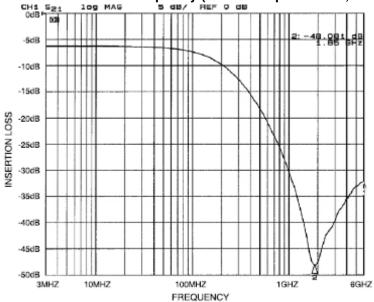
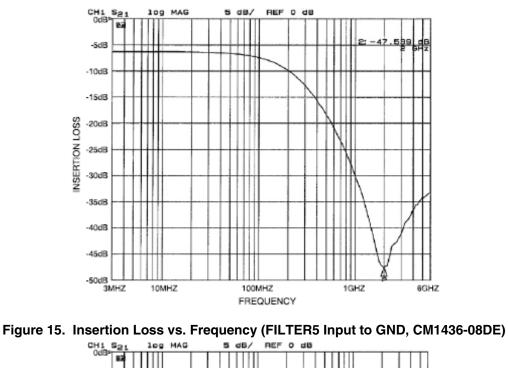


Figure 14. Insertion Loss vs. Frequency (FILTER4 Input to GND, CM1436-08DE)



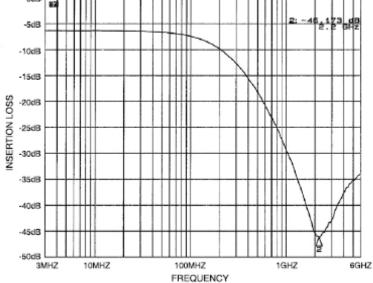


Figure 16. Insertion Loss vs. Frequency (FILTER6 Input to GND, CM1436-08DE)

Performance Information (cont'd)

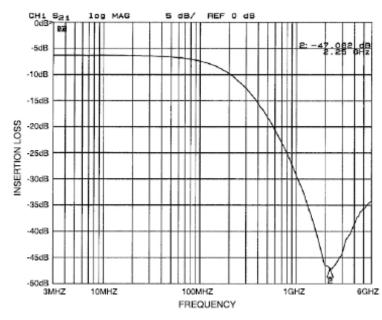


Figure 17. Insertion Loss vs. Frequency (FILTER7 Input to GND, CM1436-08DE)

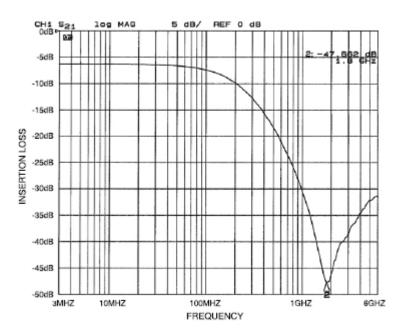


Figure 18. Insertion Loss vs. Frequency (FILTER8 Input to GND, CM1436-08DE)

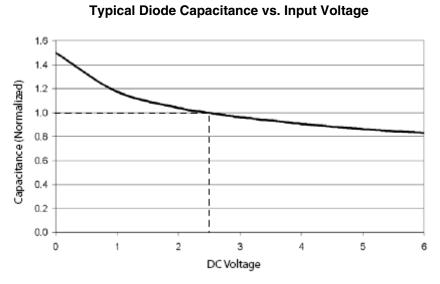


Figure 19. Filter Capacitance vs. Input Voltage (normalized to capacitance at 2.5VDC and 25°C)

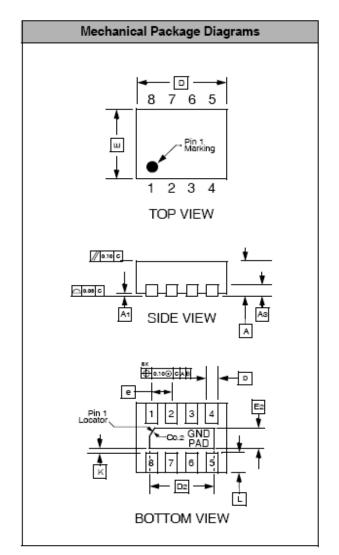
Mechanical Details

UDFN-08 Mechanical Specifications

Dimensions for the CM1630 supplied in a 8-lead, 0.4mm pitch UDFN package are presented below.

PACKAGE DIMENSIONS								
Package	UDFN							
JEDEC No.	MO-229C [†]							
Leads				8				
Dim.	N	lillimete	rs		Inches			
Dini.	Min	Nom	Max	Min	Nom	Max		
А	0.45	0.50	0.55	0.018	0.020	0.022		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
A3	С).127 RE	F	0.005 REF				
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	1.60	1.70	1.80	0.063	0.067	0.071		
D2	1.10	1.20	1.30	0.043	0.047	0.051		
E	1.25	1.35	1.45	0.049	0.053	0.057		
E2	0.30	0.40	0.50	0.012	0.016	0.020		
е	(0.40 BS	C	C	0.016 BS	C		
к	0.20			0.008				
L	0.15	0.25	0.35	0.006	0.010	0.014		
# per tape and reel	3000 pieces							
	Controlling dimension: millimeters							

⁼This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 8-Lead, 0.4mm pitch UDFN package

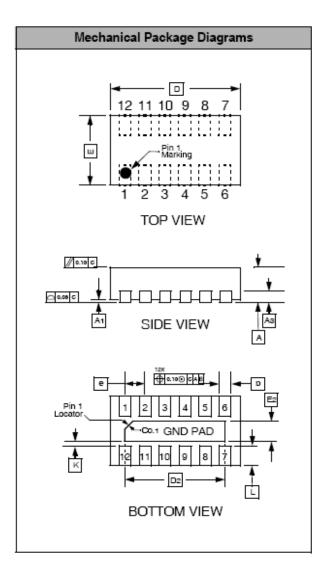
Mechanical Details (cont'd)

UDFN-12 Mechanical Specifications

Dimensions for the CM1630 suplied in a 12-lead, 0.4mm pitch UDFN package are presented below.

PACKAGE DIMENSIONS								
Package	UDFN							
JEDEC No.	MO-229C⁺							
Leads			1	12				
Dim.	N	lillimete	rs		Inches			
Dini.	Min	Nom	Max	Min	Nom	Max		
Α	0.45	0.50	0.55	0.018	0.020	0.022		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
A3	0.127 REF			0.005 REF				
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	2.40	2.50	2.60	0.094	0.098	0.102		
D2	1.90	2.00	2.10	0.075	0.079	0.083		
E	1.25	1.35	1.45	0.049	0.053	0.057		
E2	0.30	0.40	0.50	0.012	0.016	0.020		
е	(0.40 BS	С	C).016 BS	C		
к	0.20			0.008				
L	0.15	0.25	0.35	0.006	0.010	0.014		
# per tape and reel								
	Controlling dimension: millimeters							

[■]This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 12-Lead, 0.4mm pitch UDFN package

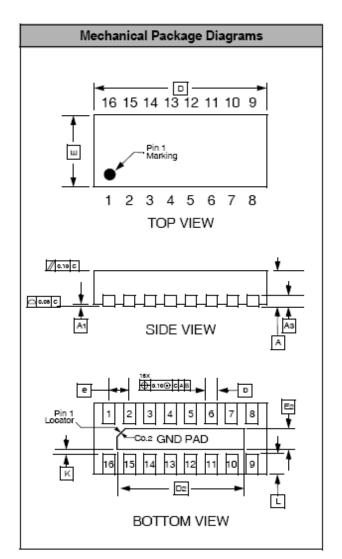
Mechanical Details (cont'd)

UDFN-16 Mechanical Specifications

Dimensions for the CM1630 supplied in a 16-lead, 0.4mm pitch UDFN package are presented below.

PACKAGE DIMENSIONS								
Package	UDFN							
JEDEC No.	MO-229C [†]							
Leads			1	16				
Dim.	N	lillimete	rs		Inches			
Dini.	Min	Nom	Max	Min	Nom	Max		
Α	0.45	0.50	0.55	0.018	0.020	0.022		
A1	0.00	0.02	0.05	0.000	0.001	0.002		
A3	0.127 REF 0.005 R).005 RE	ΞF		
b	0.15	0.20	0.25	0.006	0.008	0.010		
D	3.20	3.30	3.40	0.126	0.130	0.134		
D2	2.70	2.80	2.90	0.106	0.110	0.114		
E	1.25	1.35	1.45	0.049	0.053	0.057		
E2	0.30	0.40	0.50	0.012	0.016	0.020		
е	(0.40 BS	C	C).016 BS	C		
к	0.20			0.008				
L	0.15	0.25	0.35	0.006	0.010	0.014		
# per tape and reel	3000 pieces							
	Controlling dimension: millimeters							

[†]This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 16-Lead, 0.4mm pitch UDFN package

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative